

# Managing Inrush Current

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## ABSTRACT

In most systems, capacitors are placed throughout a design to ensure there are no voltage drops on the supply rails. When power is initially applied to the system, charging these capacitors can result in an inrush current which can exceed the nominal load current. If left unaddressed, this can cause voltage rails to fall out of regulation, resulting in the system entering an undesired state. Additionally, the inrush current can exceed the current carrying capability of board connectors as well as PCB traces, resulting in damaging the connectors and traces.

These problems can be mitigated by using Texas Instruments load switches. The load switches in the TPS229xx family are slew rate controlled to minimize inrush current. This application note explores typical causes of inrush current, problems caused by inrush current, and solutions for inrush current featuring integrated load switches.

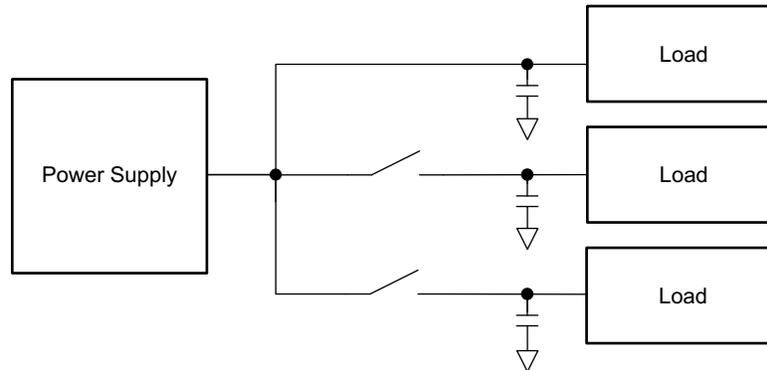
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## 1 What is Inrush Current?

An example system, shown in [Figure 1](#), uses a power supply – DC/DC, LDO, or external supply – to supply voltage to a downstream load.



**Figure 1. Typical Power Distribution**

Upon system startup, the power supply will ramp up to the regulated voltage. As the voltage increases, an inrush of current flows into the uncharged capacitors. Inrush current can also be generated when a capacitive load is switched onto a power rail and must be charged to that voltage level. The amount of inrush current into the capacitors is determined by the slope of the voltage ramp as described in [Equation 1](#):

$$I_{\text{INRUSH}} = C_{\text{LOAD}} \times \frac{dV}{dt} \quad (1)$$

Where

$I_{\text{INRUSH}}$  = amount of inrush current caused by a capacitance

$C$  = total capacitance

$dV$  = change in voltage during ramp up

$dt$  = rise time (during voltage ramp up)

### 1.1 Effects of Load Capacitance

Increasing the system capacitance to reduce transient voltage dips comes at the cost of increased inrush current generated from charging the increased capacitance. The following two figures display inrush current by showing a power supply starting up into different capacitive loads. Figure 2, below, shows a scope shot of a 3.3 V power supply starting up into a 47  $\mu\text{F}$  capacitance.

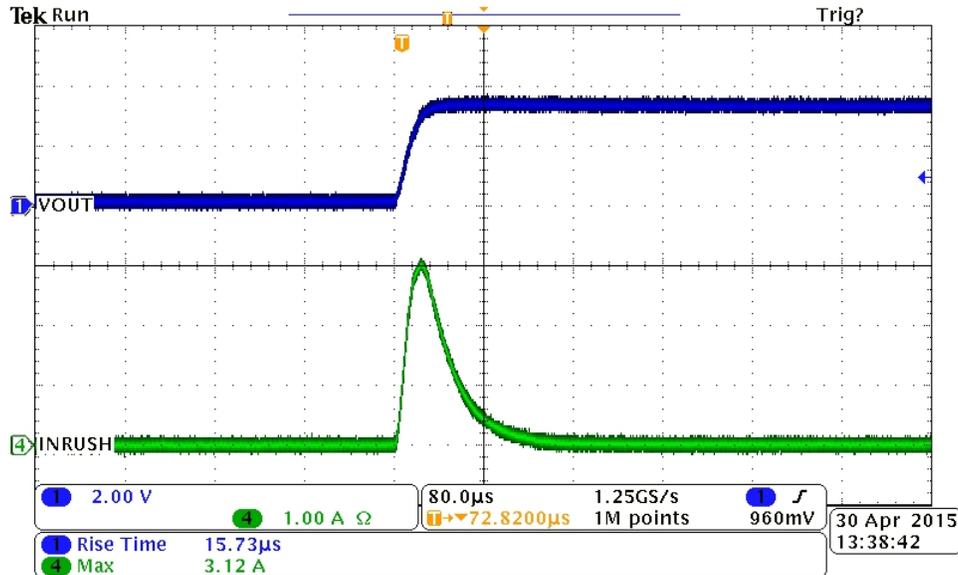


Figure 2. 3.3V Applied to a 47  $\mu\text{F}$  Capacitor

In Figure 2, as the power supply turns on and the capacitor charges, over 3.12 A of inrush current is generated. Figure 3, below, shows the same power supply turning on with a lower capacitance.

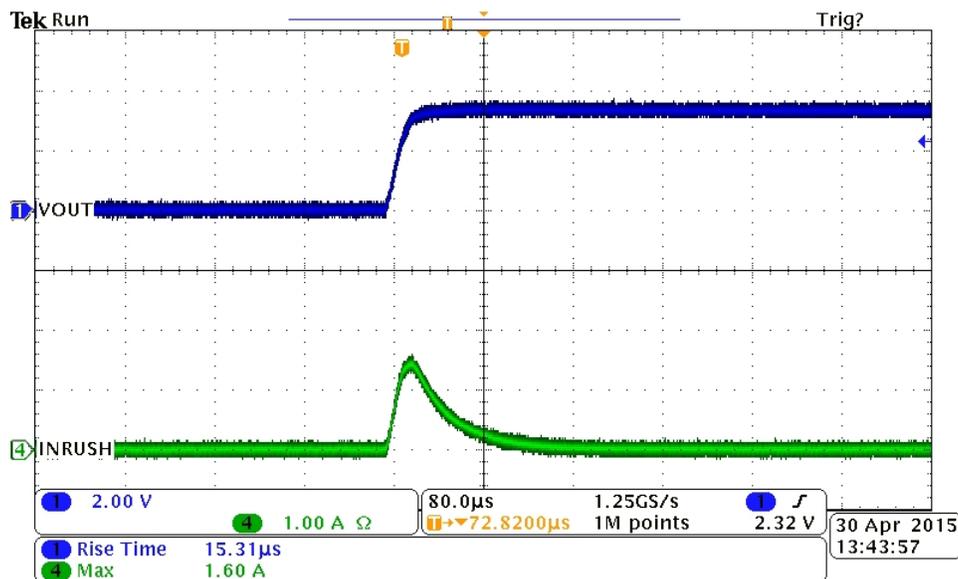


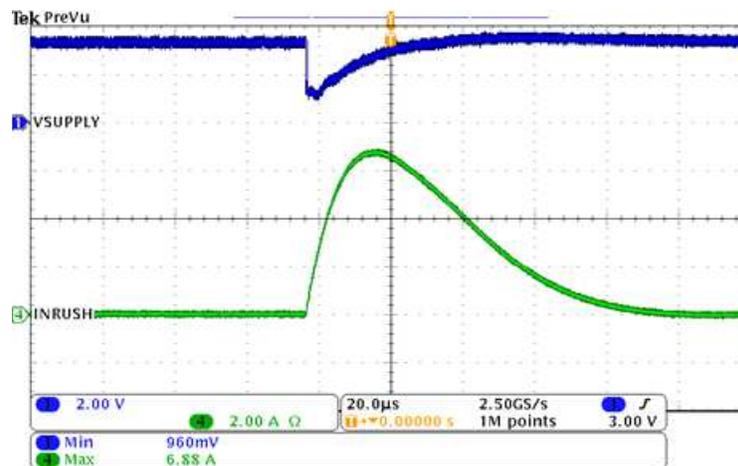
Figure 3. 3.3 V Applied to a 22  $\mu\text{F}$  Capacitor

With a reduced capacitance of 22  $\mu\text{F}$ , Figure 3 shows that the inrush current is reduced to 1.6 A. Reducing the load capacitance decreases inrush current, but it can also decrease voltage rail stability during transient current events. Certain loads may require specific output capacitance to operate, and reducing this output capacitance is not an option. Solutions to this scenario are discussed in Section 3.

## 2 Problems Caused by Inrush Current

There are two key concerns associated with inrush current. The first is exceeding the absolute maximum current ratings of the traces and components on a PCB. All connectors and terminal blocks have a specific current rating which, if exceeded, could cause damage to these parts. Likewise, all PCB traces are designed with a certain current carrying capability in mind and are also at risk to damage. When designing the PCB traces and selecting connectors, not taking the inrush current peak into account can damage the power path and lead to system failure; however, appropriately designing for a large inrush current peak will lead to thicker PCB traces and more durable connectors which can increase the size and cost of the overall design.

The second problem occurs when a capacitive load switches onto an already stable voltage rail. If the power supply cannot handle the amount of inrush current needed to charge that capacitor, then the voltage on that rail will be pulled down. [Figure 4](#) is an example of a 100  $\mu\text{F}$  capacitance being applied to a voltage supply without any slew rate control. The capacitance generates 6.88 A of inrush current and forces the voltage rail to drop from 3.3 V down to 960 mV.



**Figure 4. Power Supply Dip due to Inrush Current**

If other modules are connected to this power rail and the voltage drops, then these modules may reset themselves and put the rest of the system into an undesired state. If the voltage regulator is unable to supply enough current at turn-on, the voltage rail could collapse completely leading to system failure.

### 3 Methods of Reducing Inrush Current

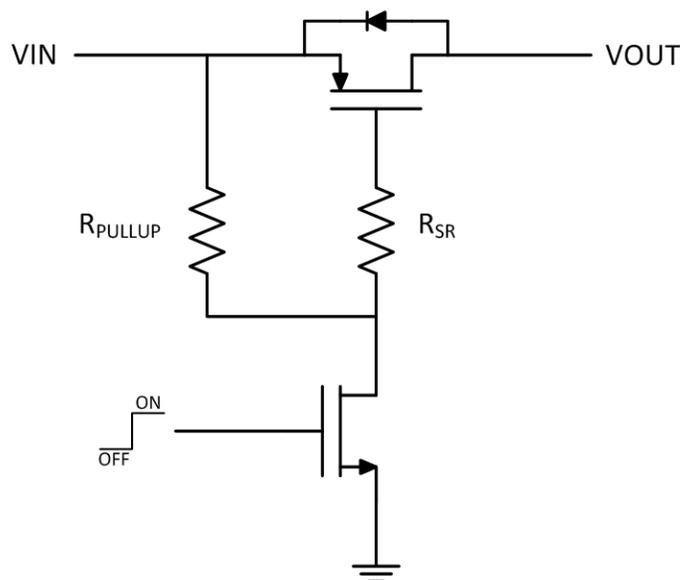
Inrush current can be reduced by increasing the voltage rise time on the load capacitance and slowing down the rate at which the capacitors charge. Three different solutions to reduce inrush current are shown below: voltage regulators, discrete components, and integrated load switches. All three of these solutions center around increasing the voltage rise time which, as shown in [Equation 1](#), leads to reduced inrush current.

#### 3.1 "Soft-start" or Voltage Regulators

Voltage regulators, DC/DC converters, and LDOs may have an integrated soft-start functionality. With this feature, the rise time can be increased, thereby reducing the inrush current. With a properly selected DC/DC converter or LDO, the inrush can be effectively managed to ensure system stability.

#### 3.2 Discrete Implementation

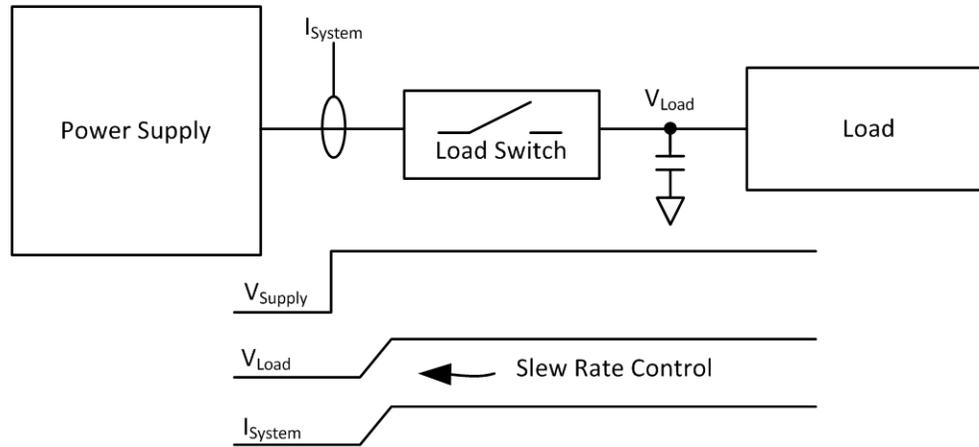
Power switching with a controlled rise time can be accomplished by using discrete circuitry and can be done in several ways. An example circuit of one solution is shown in [Figure 5](#). This particular solution requires a minimum of 4 components (2 MOSFETS, 2 resistors) and the slew rate of VOUT can be controlled by using the resistor  $R_{SR}$ . However,  $R_{SR}$  needs to be very large (in the range of  $M\Omega$ ) to have an effect on the rise time of VOUT. To be able to reduce the value of  $R_{SR}$ , an additional capacitor would need to be added.



**Figure 5. Discrete Load Switch Implementation**

### 3.3 Integrated Load Switches

Integrated load switches can be used in place of the discrete solution discussed in [Section 3.2](#). All Texas Instruments load switches ([TPS229xx products](#)) feature a controlled output slew rate to mitigate inrush current. [Figure 6](#) below shows the typical application circuit for a load switch.



**Figure 6. Typical Load Switch Application Circuit**

### 3.4 Advantages and Disadvantages of these Solutions

While all of these solutions can help to manage inrush current, they all come with their advantages and disadvantages. The least integrated of all the above solutions is the discrete implementation. When compared to its integrated counterpart, the load switch, it requires more components and a much larger solution size. By contrast, the most integrated solution is the DC/DC converter or voltage regulator with soft-start already built in. Despite its integration, adding load switches may be more beneficial for the system. If a voltage rail requires multiple capacitive loads which need to be switched individually, then multiple load switches can be used rather than multiple voltage regulators. This will reduce overall cost and solution size. Also, if the chosen voltage regulator does not come with an integrated slew rate control, then a load switch can be used before or after to provide that function. Adding a load switch to a system for inrush current control may require an additional component, but it can reduce the overall design size and cost.

## 4 Application Examples

The following application examples will use the design parameters shown in [Table 1](#):

**Table 1. Application Example 1**

Design Parameter	Example Value
Load Switch input voltage ( $V_{IN}$ )	3.3 V
Capacitive load ( $C_{LOAD}$ )	22 $\mu$ F
Maximum acceptable inrush current	600 mA

Using a  $V_{IN}$  of 3.3 V, a  $C_{LOAD}$  of 22  $\mu$ F, and a maximum acceptable inrush current of 600 mA, the required rise time for the output can be calculated.

Starting with [Equation 2](#),

$$I_{INRUSH} = C_{LOAD} \times \frac{dV}{dt} \tag{2}$$

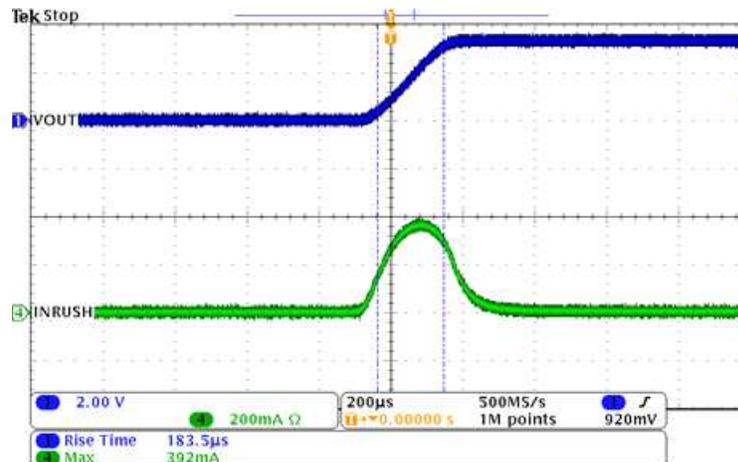
The rise time can be calculated as:

$$dt = \frac{C_{LOAD} \times dV}{I_{INRUSH}} = \frac{22 \mu\text{F} \times 3.3 \text{ V}}{600 \text{ mA}} = 121 \mu\text{s} \tag{3}$$

This means that the load switch which is chosen for this application must have a rise time of 121  $\mu$ s or higher. By visiting [www.ti.com/loadswitches](http://www.ti.com/loadswitches), all available Texas Instruments load switches can be sorted by rise time using the online parametric table. Using this method, an appropriate load switch can be chosen.

### 4.0.1 Fixed Rise Time Solution

At  $V_{IN} = 3.3 \text{ V}$ , the TPS22902B has a typical rise time of 146  $\mu$ s and can be used to ensure an inrush current lower than 600 mA. The controlled rise time of the load switch and resulting inrush current are shown in [Figure 7](#).



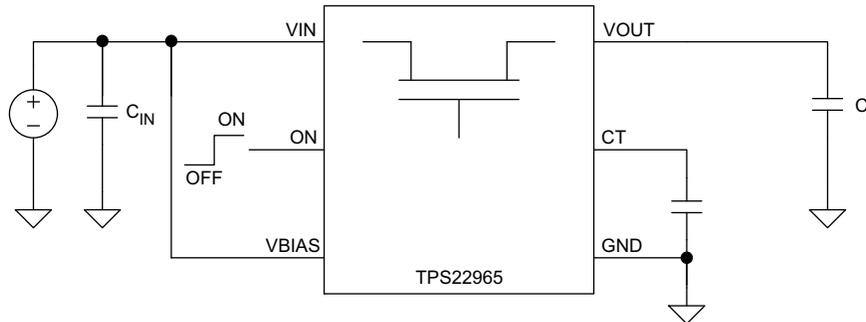
**Figure 7. TPS22902B Inrush Current**

The peak inrush current measured is 392 mA. This is well below the 600 mA design requirement and much lower than the 1.6 A seen in [Figure 3](#) without any load switches being used. By selecting the correct load switch, the inrush current is effectively managed.

Several Texas Instruments load switches with a fixed rise time have A, B, C, or D variations. These letters are used at the end of the part number to denote different rise times. An A version load switch has the fastest rise time (typically below 10  $\mu\text{s}$ ) and a D version load switch has the slowest (several milliseconds). For example, the TPS22924 load switch has B, C, and D variations with rise times of 96  $\mu\text{s}$ , 800  $\mu\text{s}$ , and 9 ms, respectively. In this application example, a rise time of greater than 121  $\mu\text{s}$  was calculated to limit the inrush current to 600 mA. The rise time of the B version would be too fast and either the C or D version could be used.

#### 4.0.2 Adjustable Rise Time Solution

All Texas Instruments load switches feature a controlled rise time, and for some load switches this rise time can be adjusted. The rise time of these devices can be increased by adding an external capacitor between the available CT pin and GND. The TPS22965 offers this feature, and its typical application schematic shown in [Figure 8](#).



**Figure 8. TPS22965 Application Circuit**

Using the datasheet for this device, the appropriate CT capacitor can be chosen to implement a desired rise time. Both the equation and table in the Adjustable Rise Time section of the [TPS22965 datasheet](#) can be used to this effect. [Figure 9](#) below shows the datasheet table which allows the user to determine the appropriate CT capacitor needed for a desired rise time.

CT (pF)	RISE TIME ( $\mu\text{s}$ ) 10% - 90%, $C_L = 0.1 \mu\text{F}$ , $C_{IN} = 1 \mu\text{F}$ , $R_L = 10 \Omega$ , $V_{BIAS} = 5 \text{V}$ TYPICAL VALUES at 25°C with a 25V X7R 10% CERAMIC CAPACITOR on CT						
	VIN = 5 V	VIN = 3.3 V	VIN = 1.8 V	VIN = 1.5 V	VIN = 1.2 V	VIN = 1.05 V	VIN = 0.8 V
0	127	93	62	55	51	46	42
220	475	314	188	162	141	125	103
470	939	637	359	304	255	218	188
1000	1869	1229	684	567	476	414	344
2200	4020	2614	1469	1211	1024	876	681
4700	8690	5746	3167	2703	2139	1877	1568
10000	18360	12550	6849	5836	4782	4089	3449

**Figure 9. TPS22965 Rise Time vs CT Capacitor**

If no CT capacitor is used, then the rise time of the load switch may be too fast to limit the inrush current to the desired peak value. Figure 10 shows the TPS22965 powering up into a 22  $\mu\text{F}$  load without any CT capacitance.

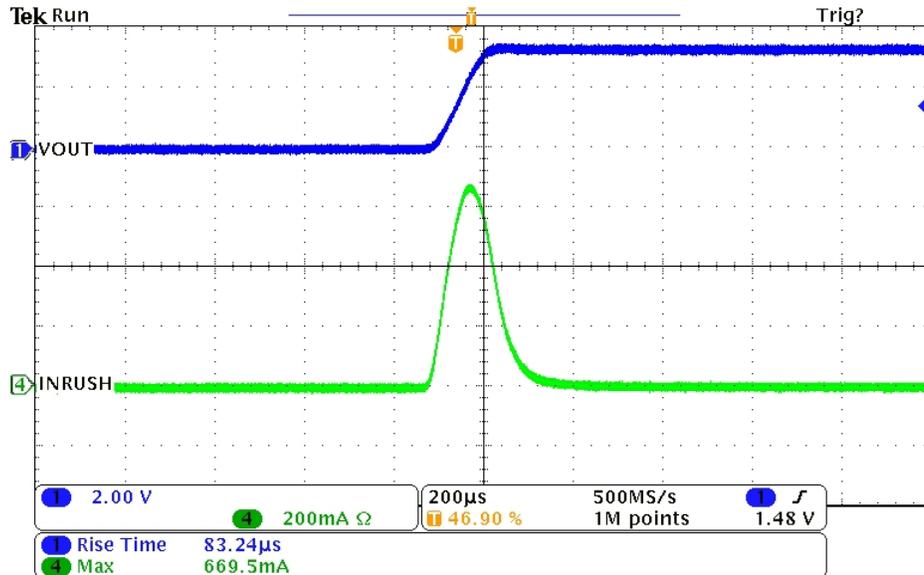


Figure 10. TPS22965 Scope Capture (CT cap = 0 pF)

With no CT capacitor, the rise time of the TPS22965 is faster than the calculated 121  $\mu\text{s}$  and results in an inrush current of about 670 mA, larger than the design goal of 600 mA. The below screenshots show the device powering up into the 22  $\mu\text{F}$  load with different CT capacitors.

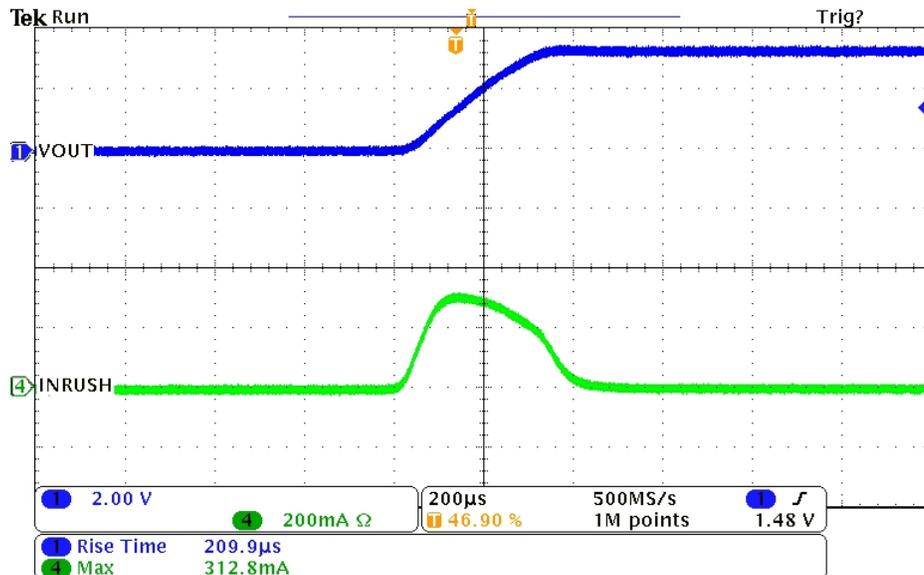


Figure 11. TPS22965 Scope Capture (CT cap = 150 pF)

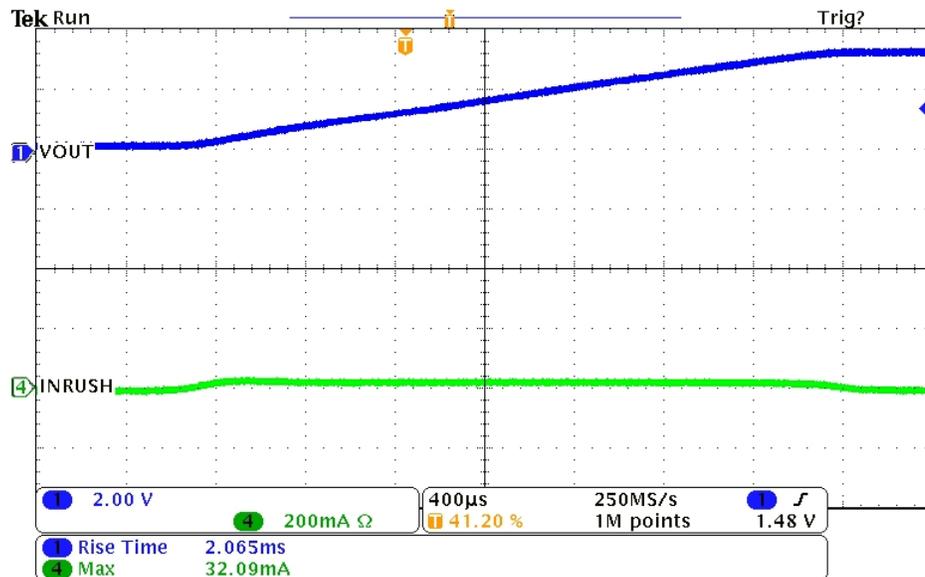


Figure 12. TPS22965 Scope Capture (CT cap = 2200 pF)

Figure 11 was taken with a CT capacitor of 150 pF and Figure 12 with 2200 pF. As the CT capacitor increases, the rise time of the device also increases and the inrush current is reduced to well below the design goal of 600 mA. While the CT pin increases the amount of flexibility in design, it does require an additional component to implement. However, this allows for a single load switch to be used across multiple designs with varying capacitive loads.

#### 4.1 Effects of Using a Slew Rate Controlled Load Switch

The following example uses a 5 V power supply which is brought down to 1.8 V using a buck converter. After the 1.8 V rail has powered up, a 100 µF capacitance is applied to the system, as shown in Figure 13.

##### 4.1.1 Response without Slew Rate Control

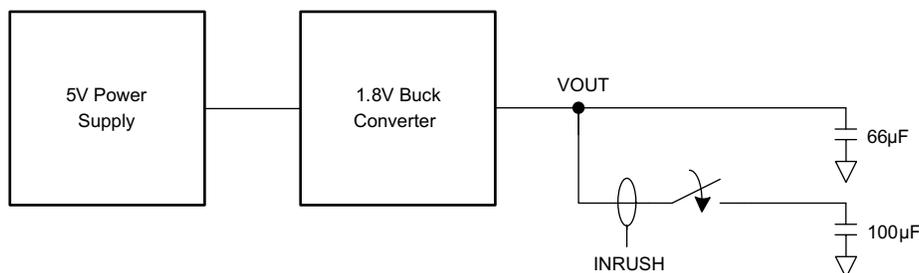


Figure 13. System Block Diagram without Slew Rate Control

With no controlled rise time, the switch does not provide any inrush current management and the following results can be observed:

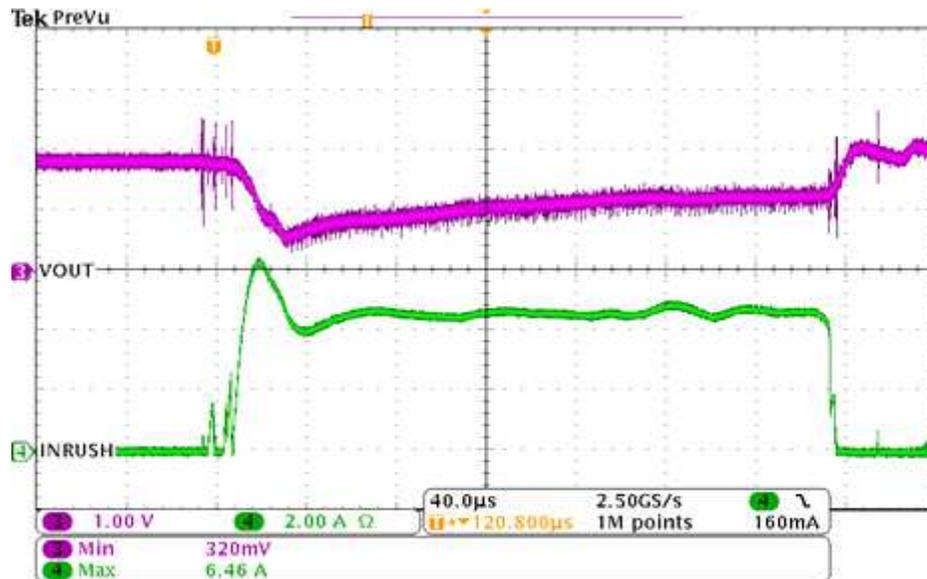


Figure 14. Inrush Current and Voltage Drop without Slew Rate Control

The inrush current generated by the 100 µF capacitor peaks at 6.46 A and brings the 1.8 V rail down to 320 mV. This 82% voltage reduction on the power rail can cause the system to reset or fail.

#### 4.1.2 Response with Slew Rate Control from a Load Switch

Figure 15 shows the same system as before, except the TPS22965 load switch from Texas Instruments with controlled rise time is used to switch the 100 µF capacitive load.

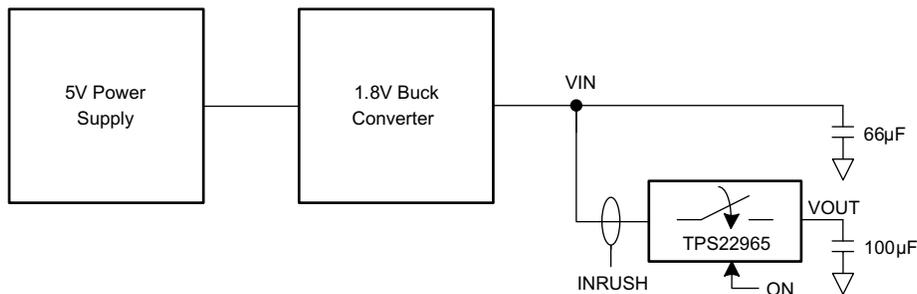
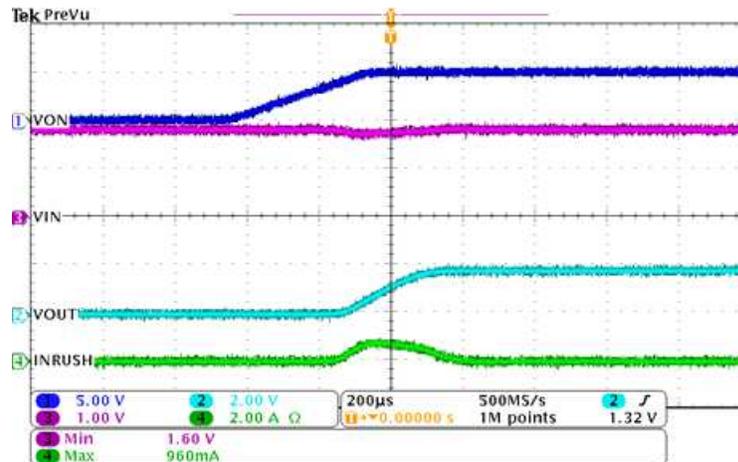


Figure 15. System Block Diagram utilizing the TPS22965

Using a 150 pF capacitor on the CT pin of the load switch, the following results can be observed:



**Figure 16. Inrush Current and Voltage Drop with Slew Rate Control**

With the controlled slew rate of the TPS22965, the maximum inrush current drops from 6.46 A to 960 mA. The 1.8 V output of the buck converter also shows no significant voltage drop.

## 5 Conclusion

Large capacitance can lead to inrush current resulting in device damage, system instability or undesired behavior. Using a TI load switch is a size and cost efficient solution for managing inrush current.

The TI load switch portfolio has a wide variety of parts with different slew rates to address the inrush currents of different system requirements. By using [Equation 1](#) and the parametric search table at [ti.com/loadswitches](http://ti.com/loadswitches), inrush current can be effectively managed by using a TI Integrated Load Switch from the TPS229xx family.

## 6 References

1. *TPS22965, 5.7-V, 6-A, 16-mΩ On-Resistance Load Switch* ([SLVSBJ0](#))
2. *TPS22902B, 3.6-V, 500-mA, 78-mΩ ON-Resistance Load Switch With Controlled Turnon* ([SLVS803](#))

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